



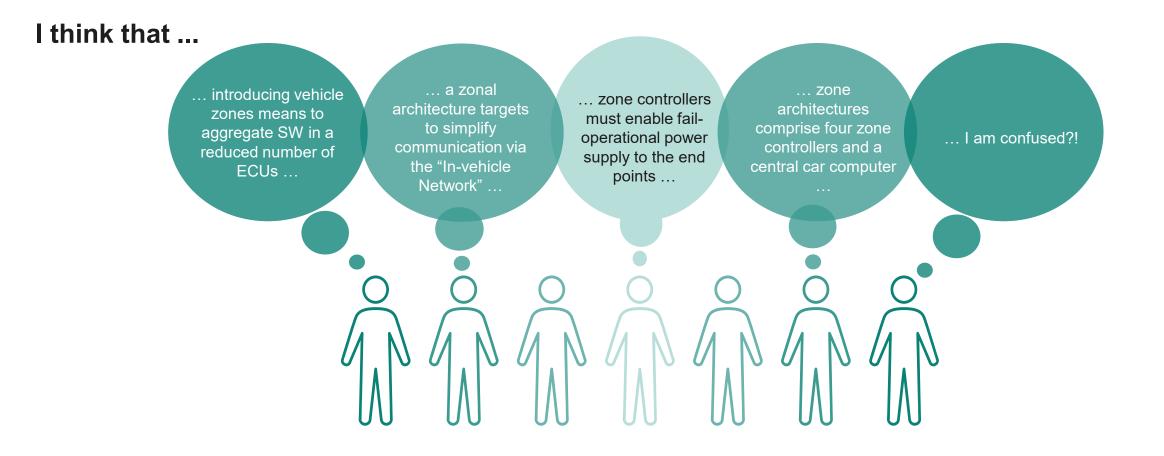
MASTERING ZONE ARCHITECTURES: YOUR GUIDE TO ELECTRIFIED POWER DISTRIBUTION SYSTEMS

Isaac Aboelsaad | Würth Elektronik eiSos GmbH & Co.KG | Specialist Product Definition Engineer Automotive & E-Mobility

Timon Busse | Infineon Technologies AG | Senior Application Manager E/E Architectures **WURTH ELEKTRONIK** MORE THAN YOU EXPECT

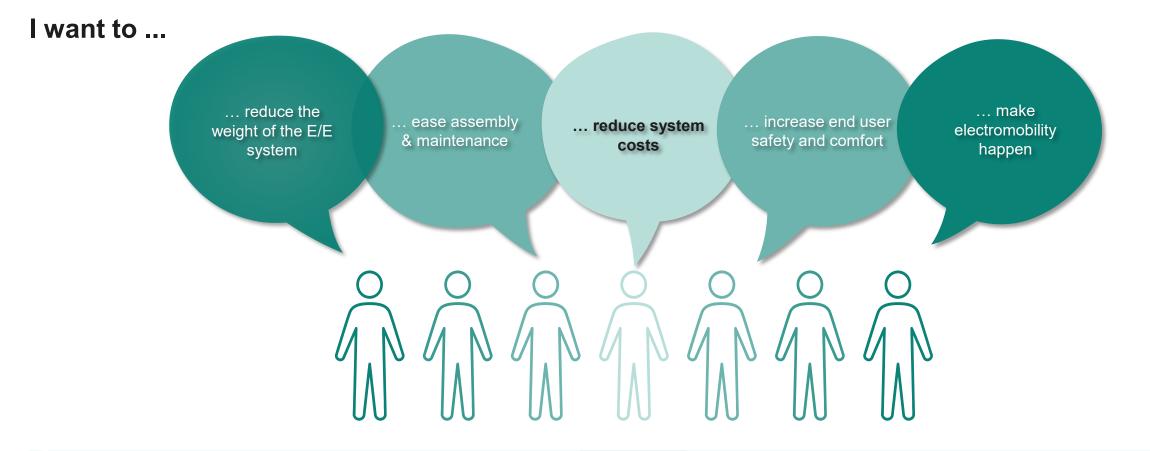
There is no clear definition of Zone architectures ...





There is no clear definition of Zone architectures ... So let's consider the underlying motivation

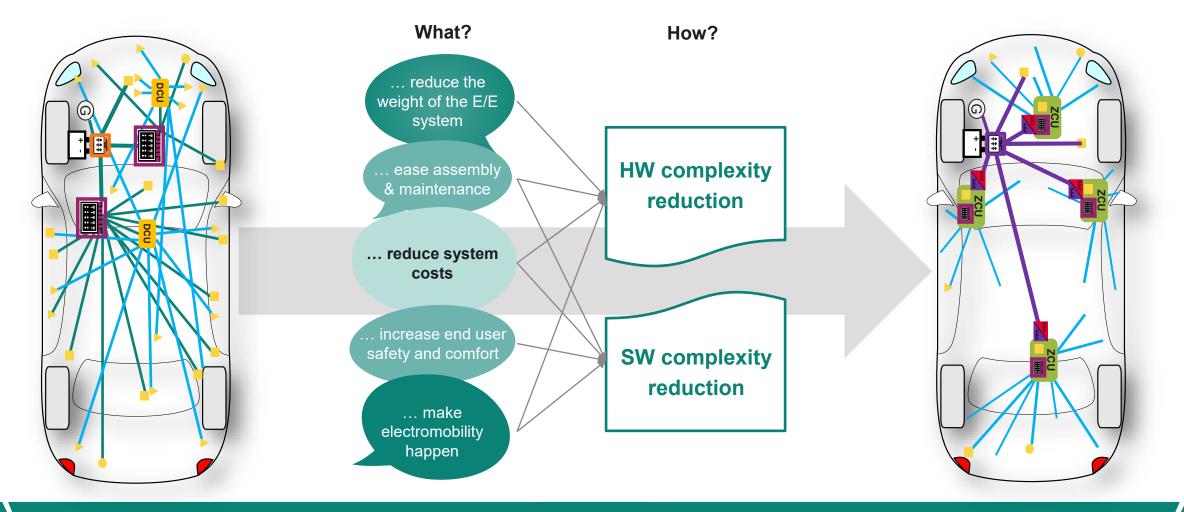




The commonly agreed goal is to build better E/E systems at less costs.

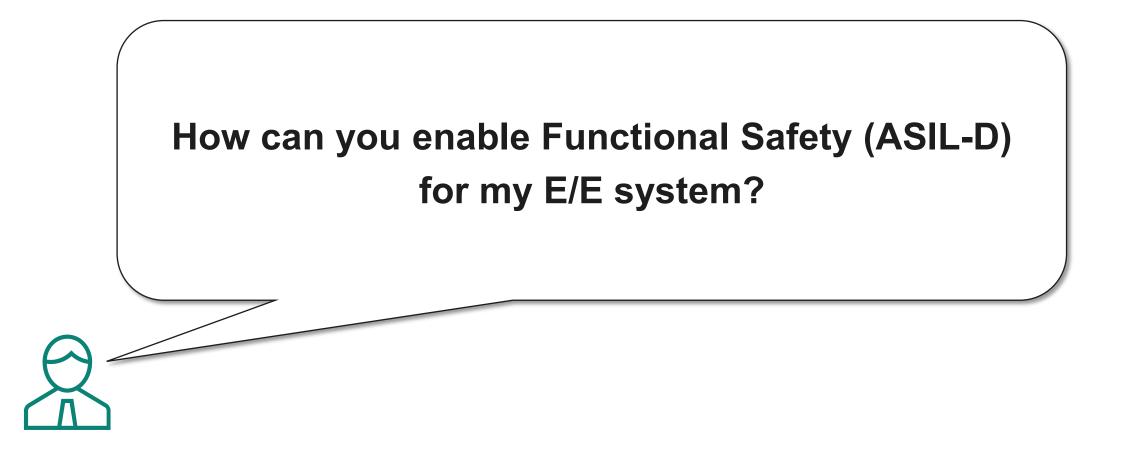
Zonal architectures from a customer point of view: "So, what do I do …"





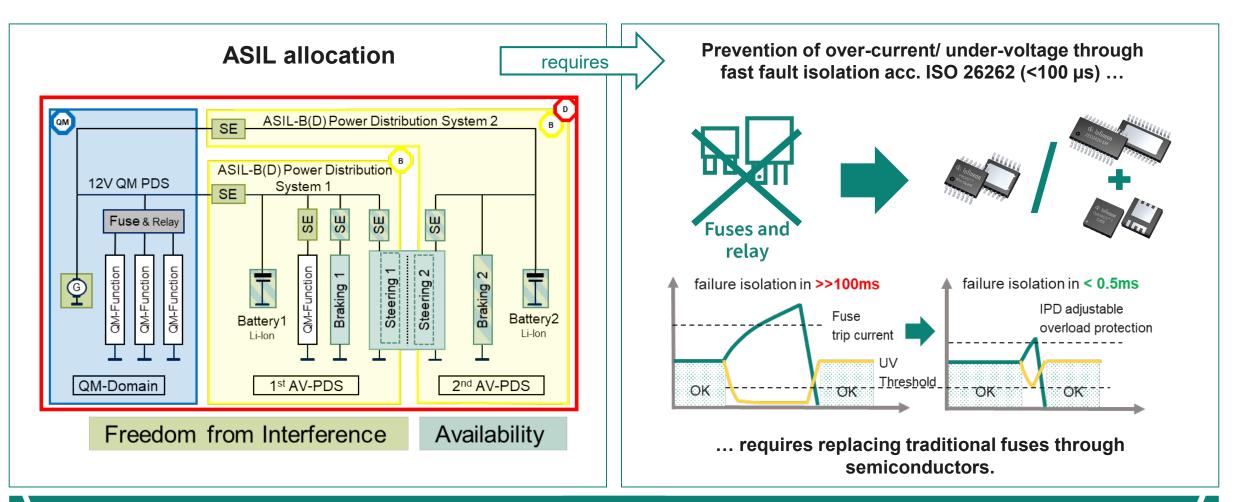
Zone architectures & Decentralized power distribution enable better E/E systems at less costs.





Fail-operational Power Distribution: The introduction of safety elements allows to secure Availability and Freedom-from-Interference





Semiconductor Safety Elements (SEs) protect from under voltage or over current and thus enable available power supply of fail-operational functions.

Smart Power Switches & Gate Driver IC's Safety conformity levels

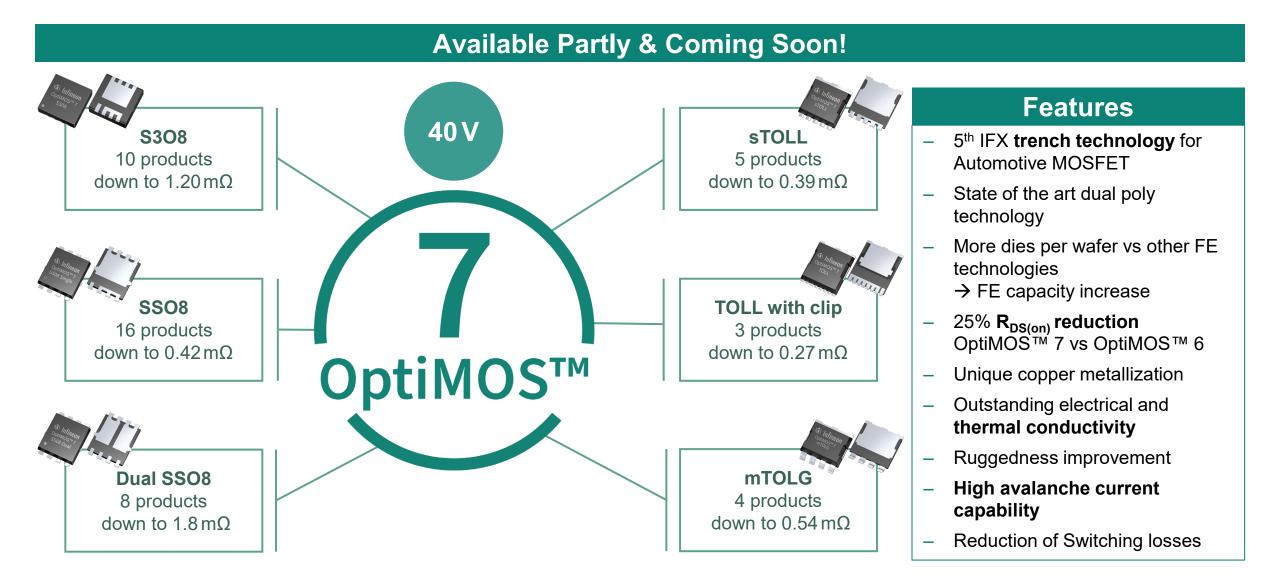


				Safety	conformity	v levels
Product Category	Product Family	Product(s)	Status	QM	ISO 26262 ready	ISO 26262 compliant
	HITFET™ +12V	BTS3x, BTF3x	Active & preferred	Х	x Ne	
Low-side Smart Power Switch	HITFET™ +24 V	BTT3x	Active & preferred		X	
	Classic HITFET™	BTS1x/ BTS3x/ BTS4x/ BSP7x	Device dependent	X		
	Classic PROFET™	BSP7x/ BTS5x/ BTS6x/ BTS7x	Device dependent	X		
	Power PROFET™ + 12V	BTS5000xx-1LUA	Active & preferred	X	x Ne	
	Power PROFET™ + 24/48V	BTH5000xx-1LUA	Coming soon	Х	X	5 V V
		BTT6x	Active & preferred	X		
	PROFET™ +24 V	BTF6070-2ERV	Active & preferred			X
High-side Smart Power Switch		BTT6035-1ERL; BTT6080-1ERL	Coming soon	Х	X	
	PROFET™ + 2 12V	BTS7xxx -xEPA/ xEPP/ xESP / xEPZ / xEPG / xEPC / xEPL / xEPR	Active & preferred	X	x	
	SPOC™ +2	BTS7xxx-4ESx / BTS7xxx-6ESx	Active & preferred	Х	X	
	PROFET™ Load Guard 12V	BTG7xxx-2EPL, BTG7xxx-1EPL	Active & preferred	Х	X	
	PROFET™ Wire Guard 12V	BTG70xxA-1EPW, BTG700xxA-1ESW	Active & preferred			ew x
		AUIR324xS	Active	Х		
Gate Driver ICs	EiceDRIVER™ APD	2ED2410-EM, 2ED4820-EM	Active & preferred	Х	X	

Subject to change – please visit Infineon webpage for latest status

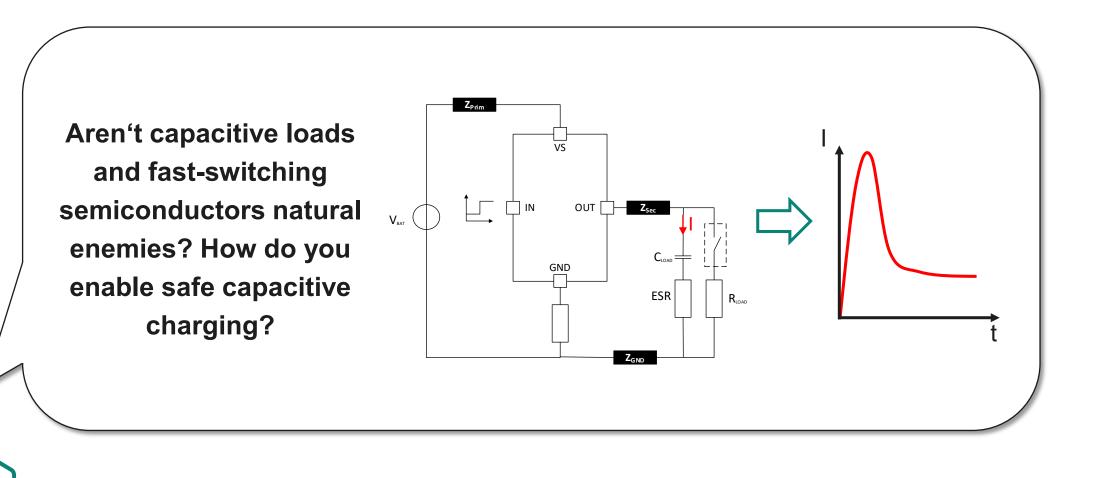
OptiMOS[™] 7 fits perfectly together with the EiceDRIVER[™] APD to support availability and freedome from interference





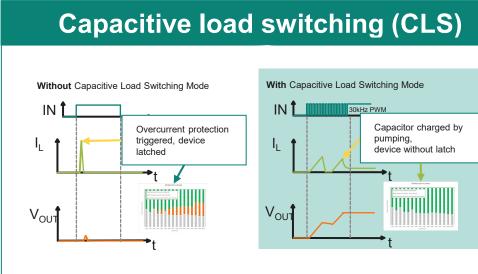
... but ...





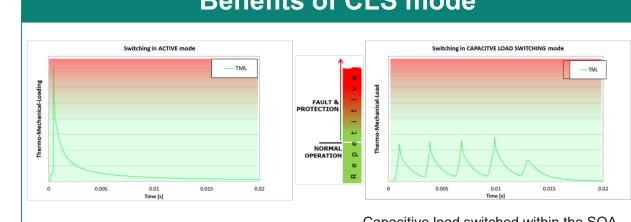
Capacitive load switching mode (CLS) enables turn on of big load capacitors without triggering device protection functions





System target:

- Switch-on of big input capacitors without over dimensioning the device for high inrush currents
- Easy adoptability and low integration effort



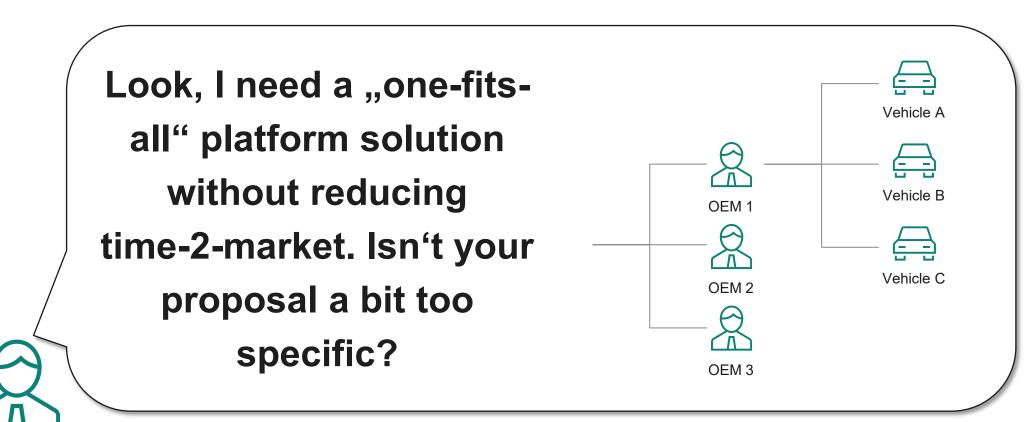
Benefits of CLS mode

Capacitive load switched within the SOA of the device

Infineon CLS mode offering:

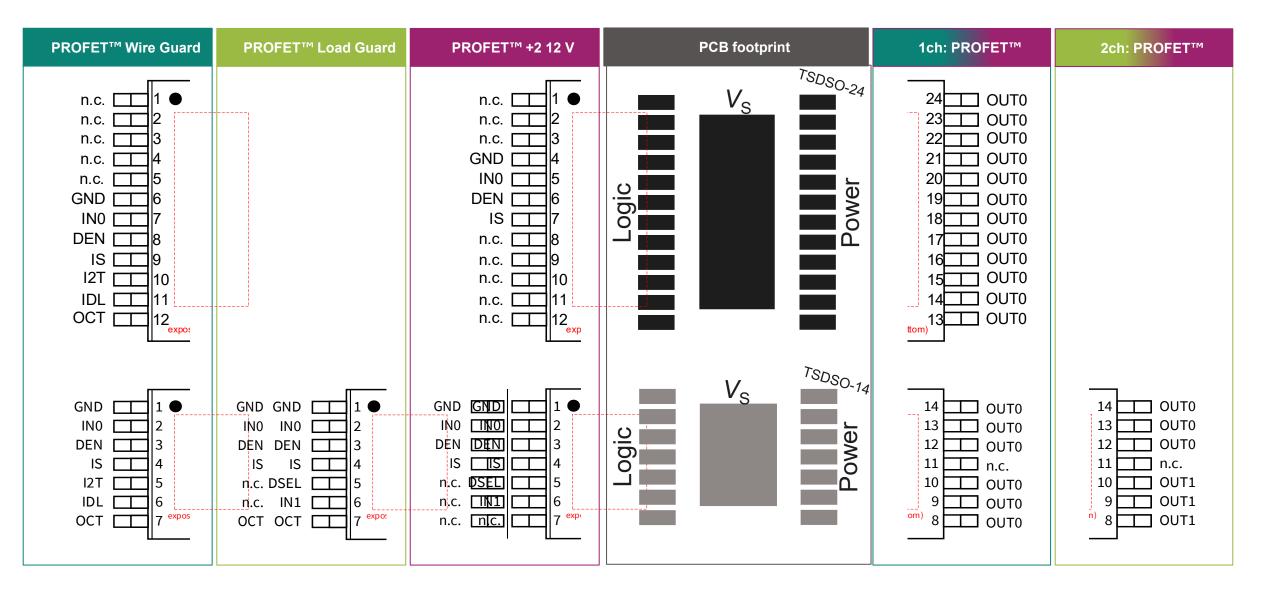
- Reduced current peak during switch-on of capacitors (protection of system supply)
- No discrete pre-charge circuitry needed (reduced external components, reduced PCB area)
- Technical e-learning available





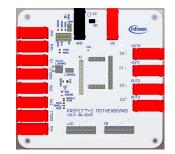
Full flexibility, modularity for the customer to always choose the componet which fits best for the application needs





Infineon is offering a broad range of hardware design support via various evaluation boards

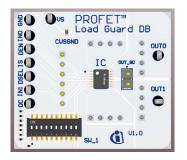




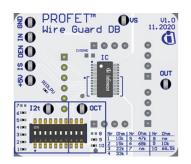
PROFET™ ONE4ALL MB V1 www.infineon.com/switches



PROFET™ +2 Daughterboards www.infineon.com/profet+2



PROFET™ Load Guard Daughterboards www.infineon.com/profetloadguard

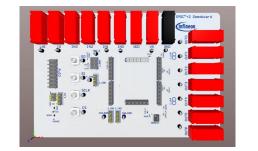


PROFET™ Wire Guard Daughterboards www.infineon.com/profetwireguard

Find more boards at www.infineon.com/switches



Power PROFET™ + Evaluation boards www.infineon.com/powerprofet



SPOC-2 MOTHERBOARD



SPOC[™] +2 Daughterboards www.infineon.com/spoc

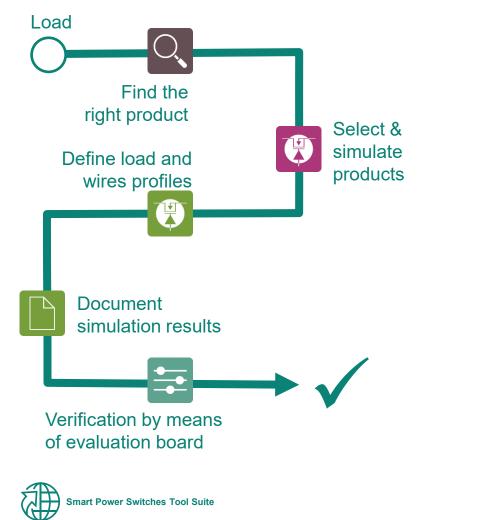


EiceDRIVER™ APD Motherboard www.infineon.com/automotive-eicedriver

Design-in tools supports starting from product selection until system simulation



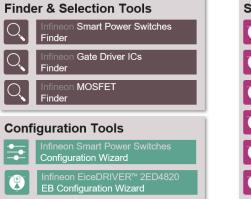


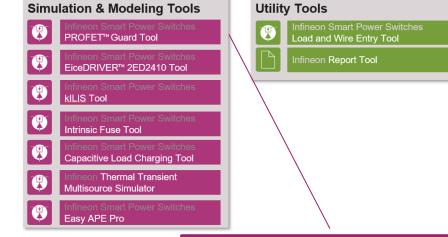






Infineon Smart Power Switches & Gate Driver Tool Suite accessible via the Infineon Developer Center Launcher

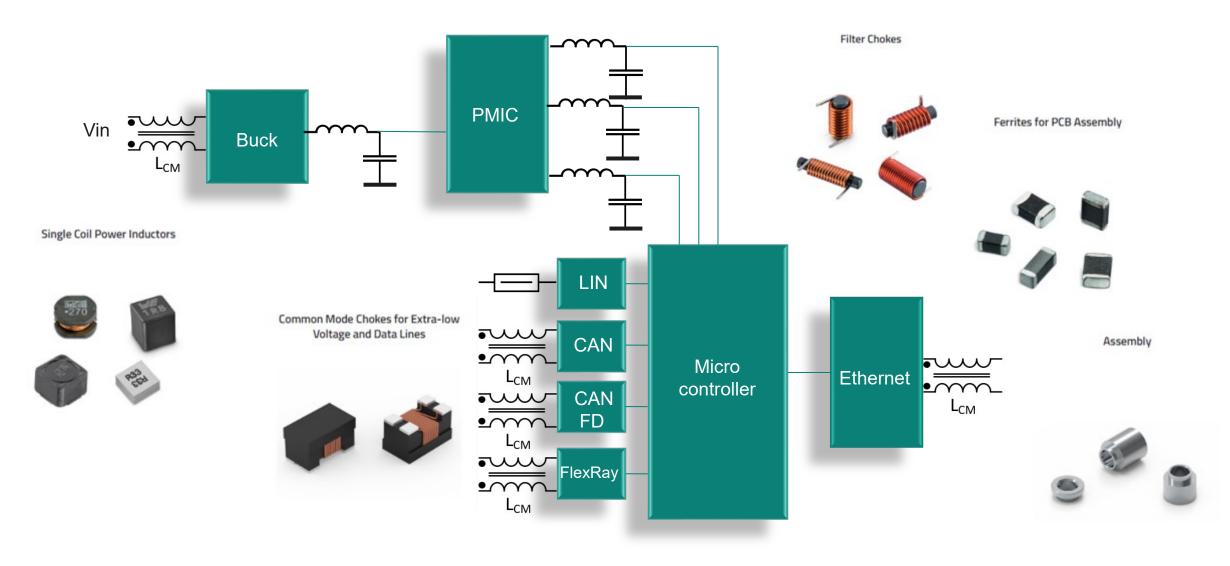






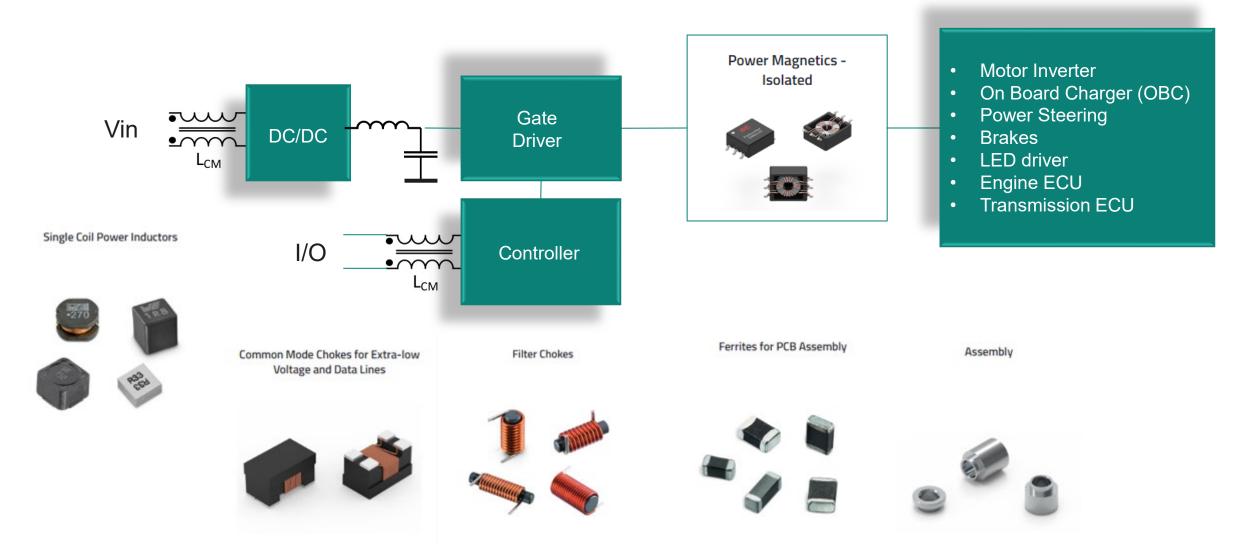


Zonal Electronic control unit ECU



Gate Drive Applications

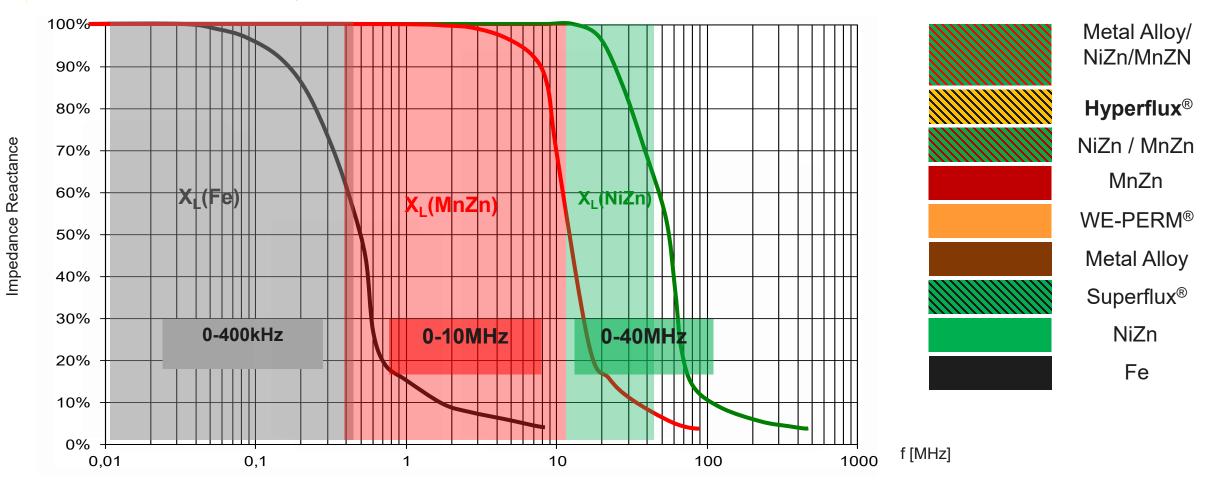






Power Inductors

Reactance vs Frequency vs material





Core Material

Core Materials	Core Loss	Perm f(DC biais)	Relative Cost	Frequency Range	Saturation Flux density (B _{sat})	Temp Stability
Iron Powder	Highest	-	Lowest	200kHz	15.000 Gauss (1,5 Tesla)	-
NiZn	Lowest	-	Low	10MHz	4.500 Gauss (0,45 Tesla)	-
WePerm®	Low	+ +	Low	3 MHz	10.000 Gauss (1.0 Tesla)	++
SuperFlux®	Medium	+++	Medium	1.0 MHz	12.000 Gauss (1,2 Tesla)	+++

Switching Frequency \Leftrightarrow Core Material



Core Material

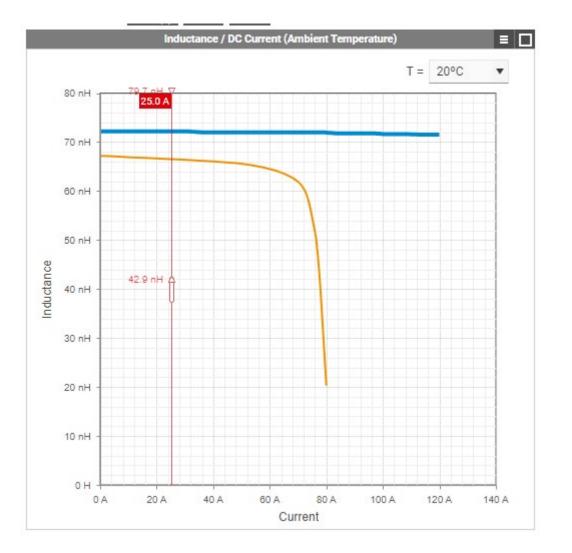
Hard Saturation vs Soft Saturation

Hard Saturation:

- 1. **Behavior**: Inductance drops drastically as soon as the saturation point is reached.
- **2. Core Material**: Typically found in inductors with winding on a solid core (e.g., high permeability iron alloys).
- **3. Application**: Less suitable for high-current transients due to abrupt saturation behavior

Soft Saturation:

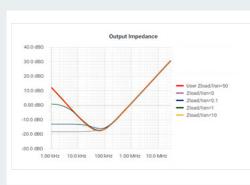
- **1. Behavior**: Inductance reduces progressively as current increases.
- 2. Core Material: Commonly used in power inductors with winding on a powdered core (e.g., ferrites).
- **3. Advantages**: Better for handling higher current transients and maintaining stable behavior at elevated temperatures



Low entry access to electronics design with REDEXPERT®



🖄 Design Tools	Product selection
EMI Filter Designer	EMC Components >
Magl ³ C Power Module Designer	Power Inductors and Magnetics >
Resonance Tank Calculation for Wireless Power	Magl ³ C Power Products
Filter Circuits	Signal & Communications >
DC/DC Converter >	Capacitors & Resistors
Flyback Transformer	Optoelectronics >
्रेन्द्रन् AC/DC Converter >	Quartz Crystals & Oscillators
$ \dot{\mu} = 0$ Wireless Connectivity and Sensors	EMC Shielding & Grounding



Filter Designer shows the output impedance for many load impedances

Our EMI Filter Designer shows the output impedance for a variety of different load / LISN impedances from 0 up to 10 0hms.

		쭈	*	F.	8
					100
W V	H _{Max} \bigtriangledown	T _{Op} \bigtriangledown	Shielded	T	AEC-Q
1.60 mm	1.00 mm	125°C	Shielded		×
1.60 mm	1.00 mm	125°C	Shielded		×
1.60 mm	1.00 mm	125°C	Shielded		×
1.60 mm	1.00 mm	125°C	Shielded		×
1.60 mm	1.00 mm	125°C	Shielded		×
1.60 mm	1.00 mm	125°C	Shielded		×

Bookmark the actual module

Add the actual module to your favorites (Login required), to have quick access directly on the REDEXPERT start page. Warning: It might save you time!



Automotive Standard Products - Portfolio

How to find them?

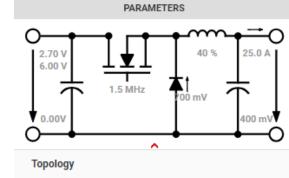
				-		-	1000	1000			-	244 (Arra)			150.0	S	1		4772		
Order Code	Z Series	Size	Y I Y Spec	Type Y Single	7 L ₀ 😵	R _{DC,typ} Υ	l _R l _s 2.95 A	sat 💎 V 5.60 A	9 X	f _{res} 😵	L 😵	W Y	H _{Max}	T _{Op} V Shielded		Automotive S	Material Metal Alloy	Assembli	Y.		
• 744383130047	WE-MAPI	1610		Single	560 nH	90.0 mΩ	2.70 A	5.20 A		150 MHz		1.60 mm		125°C Shielded	×	×	Metal Alloy	SMT	^		
 ◆744383130050 ◆744383130068 	WE-MAPI	1610		Single	680 nH	101 mΩ	2.55 A	4.80 A			1.60 mm			125°C Shielded	×	×	Metal Alloy	SMT			
•744383130082	WE-MAPI	1610		Single	820 nH	115 mΩ	2.35 A	4.60 A		115 MHz		1.60 mm		125°C Shielded	×	×	Metal Alloy	SMT			
	WE-MAPI	1610		Single	1.00 µH	127 mΩ	2.20 A	4.25 A		111 MHz		1.60 mm		125°C Shielded	×	×	Metal Alloy	SMT			
74438313012	WE-MAPI	1610		Single	1.20 µH	140 mΩ	2.10 A	4.10 A		109 MHz		1.60 mm		125°C Shielded	×	×	Metal Alloy	SMT			
◆74438313015	WE-MAPI	1610		Single	1.50 µH	189 mΩ	1.80 A	3.45 A		90.0 MHz		1.60 mm		125°C Shielded	×	×	Metal Alloy	SMT			
74438313022	WE-MAPI	1610		Single	2.20 µH	337 mΩ	1.25 A	3.25 A		70.0 MHz		1.60 mm		125°C Shielded	×	×	Metal Alloy	SMT			
744383430033	WE-MAPI	2010		Single	330 nH	40.0 mΩ	4.35 A	7.50 A	30.0 V	205 MHz	2.00 mm	1.60 mm	1.00 mm	125°C Shielded	1	×	Metal Alloy	SMT	~	_	
<															100				>	R	EDE>
Click and type or o an Order Code h Show Panel: Lva. I(T	re K vs. I(T) Z vs.	F DC Current (Ambien		T = 20°C	= _	_	т	emperature Ris	e / DC Curre	ent (Ambient Terr	mperature)	T = 20°C	=	1 k0		mpedance / Frequer	cy	≡ MOF			
an Order Code h	re K vs. I(T) Z vs.																	E MOF			
an Order Code h	re K vs. I(T) Z vs.			T = 20°C			Т	emperature Ris	e / DC Curre	ent (Ambient Ten	mperature)	T = 20°C		1 kū -		mpedance / Frequer	cy	≡ MOF			
an Order Code h	re K vs. I(T) Z vs.			T = 20°C		80 K -	Ti	emperature Ris	se / DC Curre	ent (Ambient Ten	mperature)	T = 20°C		1 KQ -		mpedance / Frequer	cy	E MOP			
an Order Code h	re K vs. I(T) Z vs.			T = 20°C			Т	emperature Ris	se / DC Curre	ent (Ambient Ten	mperature)	T = 20°C		1 k0		mpedance / Frequer	cy				
an Order Code h	re K vs. I(T) Z vs.			T = 20°C		80 K 50 K	T	emperature Ris	se / DC Curre	ent (Ambient Ten	mperature)	T = 20°C		1 kū 100 Ω -		mpedance / Frequer	cy				
an Order Code h	re K vs. I(T) Z vs.			T = 20°C		50 K -	Te	emperature Ris	ie / DC Curre	ent (Ambient Ten	mperature)	T = 20°C				mpedance / Frequer	ey				
an Order Code h Show Panel: Lvs. (7 500 nH 450 nH 400 nH	re K vs. I(T) Z vs.			T = 20°C			т	emperature Ris	se / DC Curre	ent (Ambient Ten	mperature)	T = 20°C				mpedance / Frequer	ey All a start				
an Order Code h Show Panel: Lvs. (1) 500 nH 450 nH	re K vs. I(T) Z vs.			T = 20°C		50 K - 40 K - 9522 91	To	emperature Ris	ie / DC Curre	nt (Ambient Terr	mperature)	T = 20°C				mpedance / Frequer	er				
an Order Code h Show Panel: Lvs. (7 500 nH 450 nH 400 nH	re K vs. I(T) Z vs.			T = 20°C		50 K -	T	emperature Ris	ie / DC Curre	nt (Ambient Terr	mperature)	T = 20°C		100 Q -		mpedance / Frequen	er				
an Order Code h	re K vs. I(T) Z vs.			T = _20°C		50 K	T	emperature Ris	se / DC Curre	ent (Ambient Terr	mperature)	T = 20°C		100 Q -		mpedance / Frequen	9 				
an Order Code h	re K vs. I(T) Z vs.			T = 20°C		50 K -	T	emperature Ris	ie / DC Curre	ent (Ambient Ten	mperature)	T = 20°C		100 Q -		mpedance / Frequer	G				
an Order Code h	re K vs. I(T) Z vs.			T = 20°C		50 K	7	emperature Ris	ie / DC Curre	ent (Ambient Ten	mperature)	T = 20°C		100 G -		mpedance / Frequer	cy				

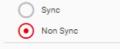


Power Inductor Selection

REDEXPERT will not only find all suitable inductors but will also calculate the expected losses and temperature rise with high accuracy

Suggestion: The "perfect" inductance wont exist anyway, order a sample for one inductance value above and below your results















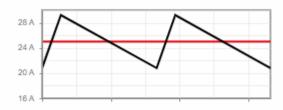






< Buck Converter										
PARAMETERS EDIT										
Input	Output	Switch	Inductor	Diode						
2.70-6.00 V	400 mV 25.0 A			700 mV						
		DETAILS	_							
I _{L,max,o} 30.0 /		L _{opt} 61.3 nH	:	I _{L,avg} 25.0 A						
74431012007										
DC	Delta	all I	L,peak	Ton						
0.16	8.49	A 2	9.2 A	109 ns						







Datasheet Values

MORE THAN YOU EXPECT

- Datasheet!
- Power Inductors do have tolerances up to 30%
- Saturation effects and Tolerances have to be considered

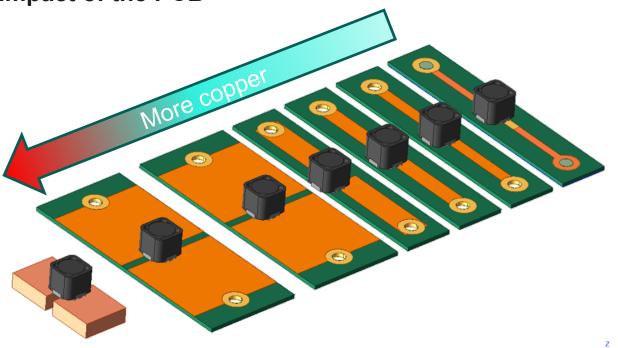
Electrical Properties:

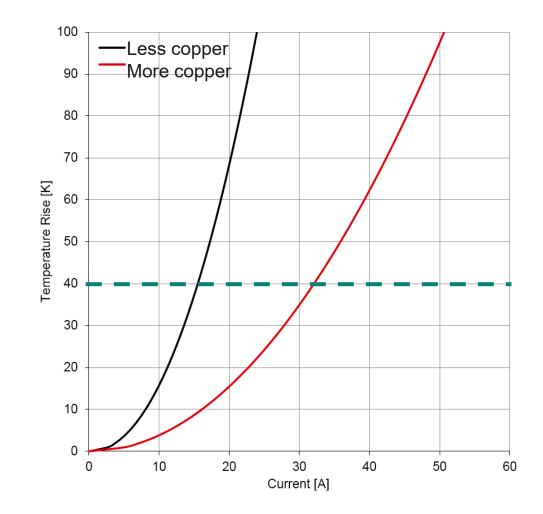
Properties		Test conditions	Value	Unit	Tol.
Inductance	L	100 kHz/ 100 mA	72	nH	±20%
Rated Inductance	L _R	100 kHz/ 10mA/ 30.0 A	71	nH	typ.
Rated Current	R	$\Delta T = 40 \text{ K}$	30	А	max.
Performance Rated Current ¹⁾	I _{RP,40K}	ΔT = 40 K	76.1	А	max.
Saturation Current @ 10%	I _{SAT, 10%}	ΙΔL/LI < 10 %	62	А	typ.
Saturation Current @ 30%	I _{SAT,30%}	ΙΔL/LI < 30 %	64	А	typ.
DC Resistance	R _{DC}	@ 20 °C	0.235	mΩ	±7%
Self Resonant Frequency	f _{res}		150	MHz	typ.

¹⁾ refer to IEC 62024-2-2020



Rated current Impact of the PCB

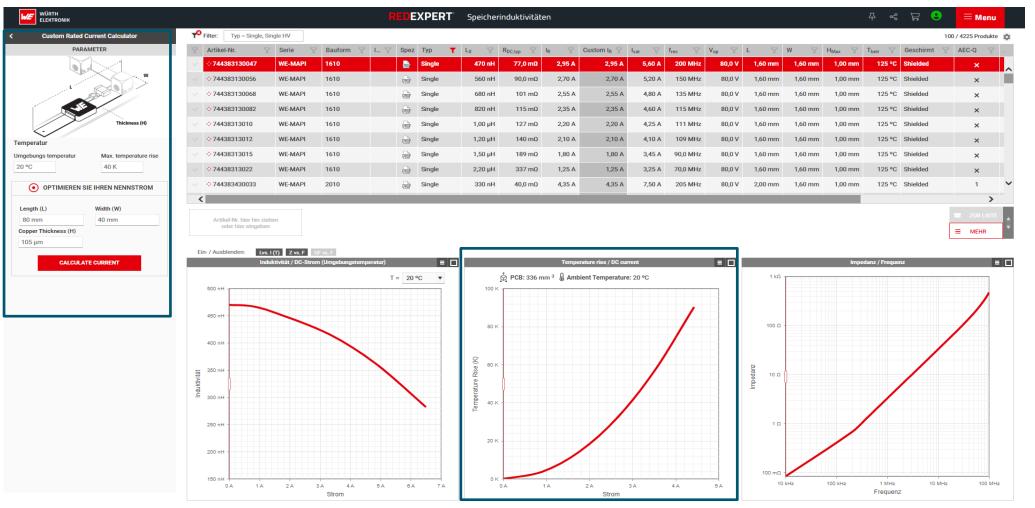






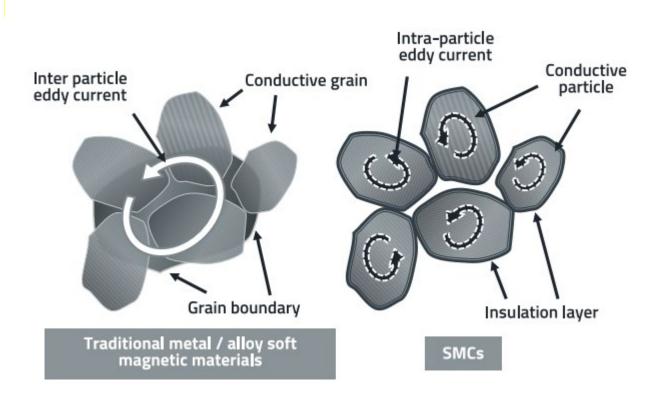
Rated current

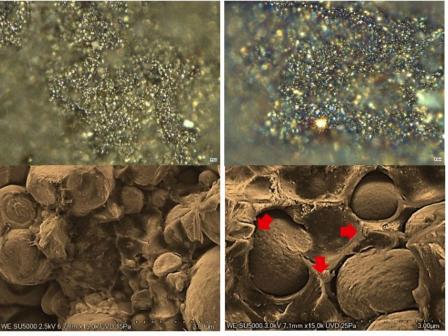
And more....



Thermal Aging

Molded Power Inductors





a. Left Column: Before test

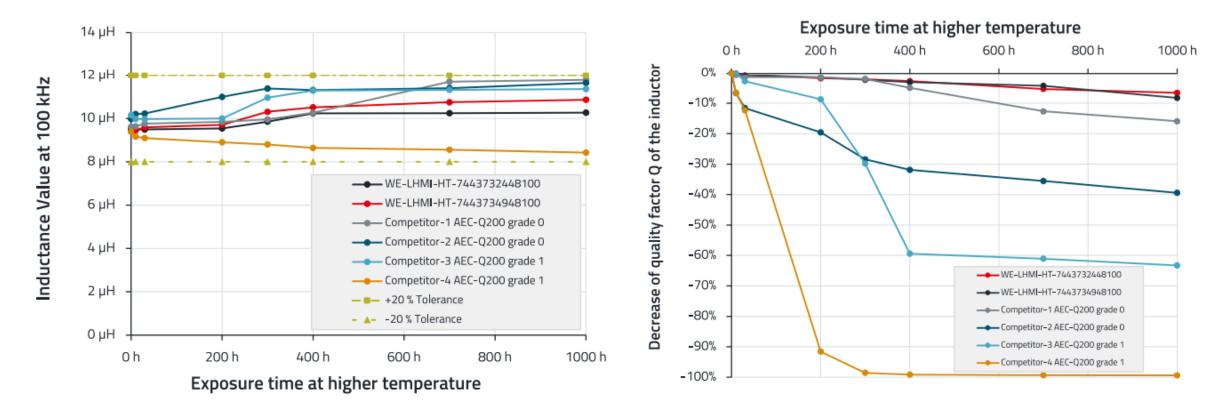
b. Right Column: After test

App Note: ANP128



Thermal Aging





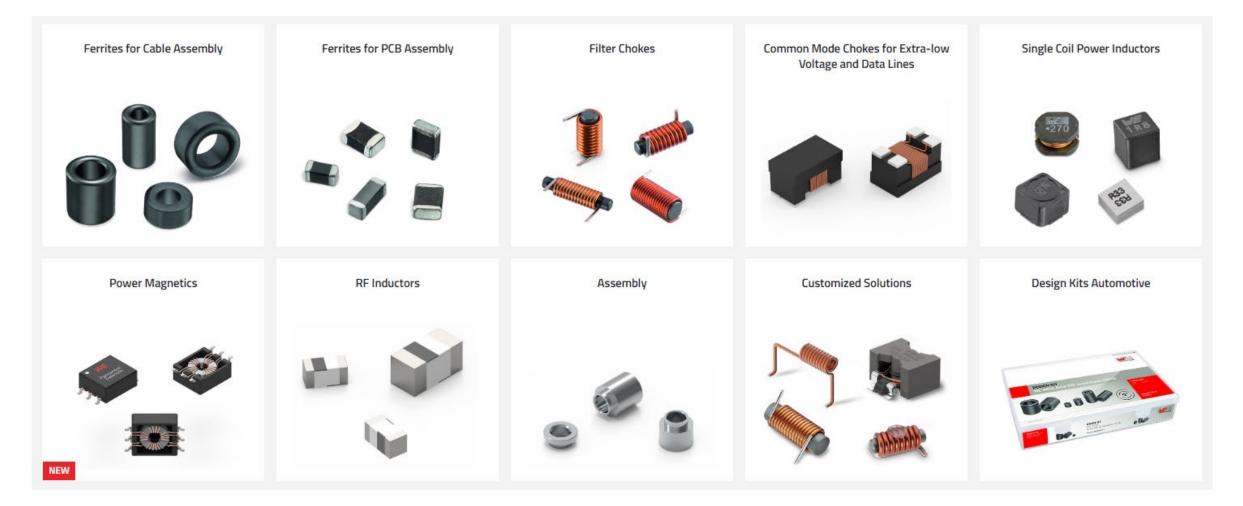
a. Inductance L value at 100 kHz during 1000 h at 200 °C.

See Also: <u>ANP126</u> | Voltage specification for molded inductors

b. Decrease of Q value at 2 MHz during 1000 h at 200 °C.



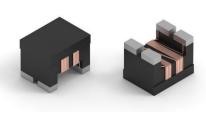
Automotive Standard Products - Portfolio





Product New Release

SIGNAL & COMMUNICATION



WE-CNSA (SMD Common Mode Choke for Data line) Size 1210 CAN / CAN FD BUS Certification A2B Automotive

EMC COMPONENTS

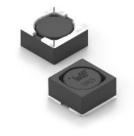


WE-OEFA LFS (Oval EMC Suppressor Bead MnZN Core) Size 65 mm OD Impedance up to 112 Ω (100MHz)

POWER APPLICATIONS



WE-HCFA-T (THT High Current Inductor) Size 3521/3540 Very Low RDC from 0.35mΩ Saturation Current up to 175A



WE-HEPA (Tiny Shielded Power Inductor) Size 6030/5030 Up to 2 A Full Automated



WE-LHCA (SMD Molded Power Inductor) Size 7030/1040/1365/1770 Soft Saturation current up to 95 A Low RDC



3 things to remember!

Smart power switches, gate driver ICs & MOSFETs are the better fuses and thus enable safe and modern power distribution systems Along with semiconductors comes a need for complementary passive components that helps achieving high efficiency and reduce EMC problems





Check out Infineon's and Würth's design-in resources via the respective webpages and reach out to your sales representatives to launch your Power Distriution System design!





THANK YOU

WURTH ELEKTRONIK MORE THAN YOU EXPECT